Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material: Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method:** Terminal **Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic:

200.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited and 300.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited and 6.0 peak positive gate voltage and 6.0 peak negative gate voltage and 300.0 forward voltage, peak

Current Rating Per Characteristic:

10.00 amperes source cutoff current peak and 0.10 amperes source cutoff current minor and 1.60 amperes forward current, average of standard range

Power Rating Per Characteristic:

100.0 milliwatts small-signal input power, common-collector blank and 10.0 milliwatts small-signal input power, common-collector universal

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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